## C4D15120A-Silicon Carbide Schottky Diode Z-REC ${ }^{\text {TM }}$ Rectifier

$$
\begin{aligned}
& \mathbf{V}_{\mathrm{RRM}}=1200 \mathrm{~V} \\
& \mathbf{I}_{\mathbf{F}} \mathbf{T}_{\mathbf{c}}<\mathbf{1 3 5}{ }^{\circ} \mathbf{C}=20 \mathrm{~A} \\
& \mathbf{Q}_{\mathbf{c}}=\quad 96 \mathrm{nC}
\end{aligned}
$$

## Features

- 1.2 kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Swtitching


## Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway


## Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives

Package


TO-220-2


| Part Number | Package | Marking |
| :---: | :---: | :---: |
| C4D15120A | TO-220-2 | C4D15120 |

Maximum Ratings ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Value | Unit | Test Conditions | Note |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {RRM }}$ | Repetitive Peak Reverse Voltage | 1200 | V |  |  |
| $\mathrm{V}_{\text {RSM }}$ | Surge Peak Reverse Voltage | 1300 | V |  |  |
| $V_{\text {R }}$ | DC Peak Reverse Voltage | 1200 | V |  |  |
| $\mathrm{I}_{\mathrm{F}}$ | Continuous Forward Current | $\begin{aligned} & \hline 15 \\ & 20 \end{aligned}$ | A | $\mathrm{T}_{\mathrm{C}}<150^{\circ} \mathrm{C}$, no AC component $\mathrm{T}_{\mathrm{C}}<135^{\circ} \mathrm{C}$, no AC component |  |
| $\mathrm{I}_{\text {FRM }}$ | Repetitive Peak Forward Surge Current | $\begin{aligned} & 68 \\ & 44 \end{aligned}$ | A | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine Pulse $\mathrm{T}_{\mathrm{C}}=110^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine Pulse |  |
| $\mathrm{I}_{\text {FSM }}$ | Non-Repetitive Forward Surge Current | $\begin{gathered} 100 \\ 85 \\ \hline \end{gathered}$ | A | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine Pulse $\mathrm{T}_{\mathrm{C}}=110^{\circ} \mathrm{C}$, $\mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine Pulse |  |
| $\mathrm{P}_{\text {tot }}$ | Power Dissipation | $\begin{gathered} 192 \\ 83 \end{gathered}$ | W | $\begin{aligned} & \mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{C}}=110^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ |  |
| $\mathrm{T}_{\mathrm{c}}$ | Maximum Case Temperature | 135 | ${ }^{\circ} \mathrm{C}$ |  |  |
| T, | Operating Junction Range | $\begin{gathered} -55 \text { to } \\ +175 \end{gathered}$ | ${ }^{\circ} \mathrm{C}$ |  |  |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature Range | $\begin{aligned} & -55 \text { to } \\ & +135 \end{aligned}$ | ${ }^{\circ} \mathrm{C}$ |  |  |
|  | TO-220 Mounting Torque | $\begin{gathered} 1 \\ 8.8 \end{gathered}$ | $\underset{\mathrm{Ibf} \text {-in }}{\mathrm{Nm}}$ | M3 Screw 6-32 Screw |  |

## Electrical Characteristics

| Symbol | Parameter | Typ. | Max. | Unit | Test Conditions | Note |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{F}$ | Forward Voltage | $\begin{aligned} & 1.6 \\ & 2.3 \end{aligned}$ | $\begin{gathered} 1.8 \\ 3 \end{gathered}$ | V | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=15 \mathrm{~A} \\ & \mathrm{I}_{\mathrm{F}}=15 \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{J}}=175^{\circ} \mathrm{C} \end{aligned}$ |  |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | $\begin{gathered} 35 \\ 120 \end{gathered}$ | $\begin{aligned} & 200 \\ & 300 \end{aligned}$ | $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{R}}=1200 \vee \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{R}}=1200 \mathrm{~V} \quad \mathrm{~T}_{\mathrm{J}}=175^{\circ} \mathrm{C} \end{aligned}$ |  |
| $\mathrm{Q}_{\mathrm{C}}$ | Total Capacitive Charge | 96 |  | nC | $\begin{aligned} & \mathrm{V}_{\mathrm{R}}=1200 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=15 \mathrm{~A} \\ & \mathrm{~d} i / \mathrm{d} t=200 \mathrm{~A} / \mu \mathrm{s} \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ |  |
| C | Total Capacitance | $\begin{gathered} 1200 \\ 70 \\ 50 \\ \hline \end{gathered}$ |  | pF | $\begin{aligned} & \mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{R}}=400 \mathrm{~V}_{1} \mathrm{~T}_{\mathrm{J}}=25^{\circ}{ }^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{R}}=800 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ |  |

1. Note:This is a majority carrier diode, so there is no reverse recovery charge.

## Thermal Characteristics

| Symbol | Parameter | Typ. | Max. | Unit | Test Conditions | Note |
| :---: | :--- | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\theta \mathrm{J} \mathrm{C}}$ | Thermal Resistance from Junction <br> to Case | 0.78 |  | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |  |  |

## Typical Performance



Figure 1. Forward Characteristics


Figure 2. Reverse Characteristics

## Typical Performance



Figure 3. Current Derating


Figure 5. Recovery Charge vs. Reverse Voltage


Figure 4. Power Derating


Figure 6. Capacitance vs. Reverse Voltage

## Typical Performance



Figure 7. Transient Thermal Impedance

$$
V f_{T}=V_{T}+I f * R_{T}
$$


$\mathrm{V}_{\mathrm{T}}=0.97+\left(\mathrm{T}_{\mathrm{j}} *-2.12 * 10^{-3}\right)$
$\mathrm{R}_{\mathrm{T}}=0.031+\left(\mathrm{T}_{\mathrm{j}} * 3.92 * 10^{-4}\right)$
-n!いい-
$V_{T} \quad R_{T}$

Note: $T_{j}$ is diode junction temperature in degrees Celsius

## Package Dimensions

Package TO-220-2


|  | POS | Inches |  | Millimeters |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Max | Min | Max |
|  | A | . 381 | . 410 | 9.677 | 10.414 |
|  | B | . 235 | . 255 | 5.969 | 6.477 |
|  | C | .100 | . 120 | 2.540 | 3.048 |
|  | D | . 223 | . 337 | 5.664 | 8.560 |
|  | E | . 590 | .615 | 14.986 | 15.621 |
| $\overrightarrow{\rightarrow 0} \mid \leftarrow X$ | F | .143 | . 153 | 3.632 | 3.886 |
|  | G | 1.105 | 1.147 | 28.067 | 29.134 |
| $Y \longrightarrow$ | H | . 500 | . 550 | 12.700 | 13.970 |
|  | J | R 0.197 |  | R 0.197 |  |
|  | L | . 025 | . 036 | . 635 | . 914 |
|  | M | . 045 | . 055 | 1.143 | 1.397 |
|  | N | .195 | . 205 | 4.953 | 5.207 |
|  | P | .165 | . 185 | 4.191 | 4.699 |
|  | Q | . 048 | . 054 | 1.219 | 1.372 |
|  | S | $3^{\circ}$ | $6^{\circ}$ | $3^{\circ}$ | $6^{\circ}$ |
|  | T | $3^{\circ}$ | $6^{\circ}$ | $3^{\circ}$ | $6^{\circ}$ |
|  | U | $3^{\circ}$ | $6^{\circ}$ | $3^{\circ}$ | $6^{\circ}$ |
|  | V | .094 | . 110 | 2.388 | 2.794 |
|  | W | . 014 | . 025 | . 356 | . 635 |
|  | X | $3^{\circ}$ | $5.5{ }^{\circ}$ | $3^{\circ}$ | $5.5^{\circ}$ |
|  | Y | .385 | .410 | 9.779 | 10.414 |
|  | Z | .130 | .150 | 3.302 | 3.810 |

NOTE:

1. Dimension $L, M, W$ apply for Solder Dip Finish

Recommended Solder Pad Layout


TO-220-2

| Part Number | Package | Marking |
| :---: | :---: | :---: |
| C4D15120A | TO-220-2 | C4D15120 |

